

TOSHIBA Transistor Silicon PNP Epitaxial Type

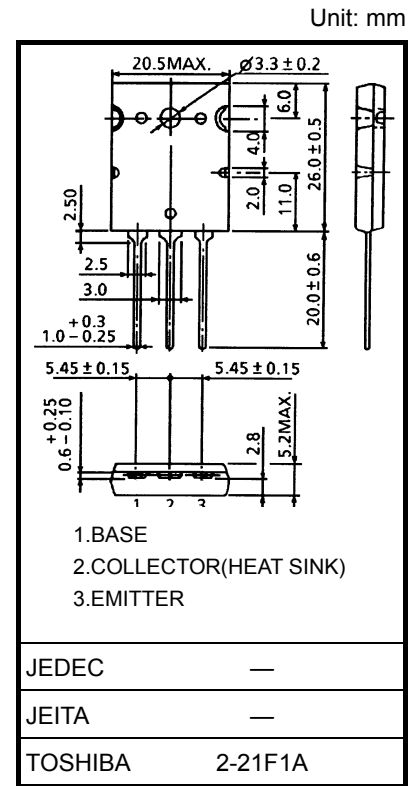
TTA1943

Power Amplifier Applications

- High collector voltage: $V_{CEO} = -230$ V (min)
- Complementary to TTC5200
- Recommended for 100-W high-fidelity audio frequency amplifier output stage.

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	-230	V
Collector-emitter voltage	V_{CEO}	-230	V
Emitter-base voltage	V_{EBO}	-5	V
Collector current	I_C	-15	A
Base current	I_B	-1.5	A
Collector power dissipation ($T_c=25^\circ\text{C}$)	P_C	150	W
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature range	T_{stg}	-55 to 150	$^\circ\text{C}$



Weight : 9.75 g (typ)

Note1 : Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

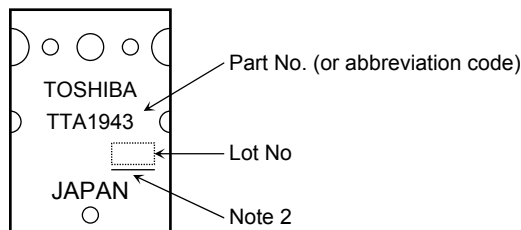
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production
2009-03

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I_{CBO}	$V_{CB} = -230\text{ V}, I_E = 0$	—	—	-5.0	μA
Emitter cut-off current	I_{EBO}	$V_{EB} = -5\text{ V}, I_C = 0$	—	—	-5.0	μA
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = -50\text{ mA}, I_B = 0$	-230	—	—	V
DC current gain	$h_{FE(1)}$	$V_{CE} = -5\text{ V}, I_C = -1\text{ A}$	80	—	160	
	$h_{FE(2)}$	$V_{CE} = -5\text{ V}, I_C = -7\text{ A}$	35	—	—	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -8\text{ A}, I_B = -0.8\text{ A}$	—	—	-3.0	V
Base-emitter voltage	V_{BE}	$V_{CE} = -5\text{ V}, I_C = -7\text{ A}$	—	—	-1.5	V
Transition frequency	f_T	$V_{CE} = -5\text{ V}, I_C = -1\text{ A}$	—	30	—	MHz
Collector output capacitance	C_{ob}	$V_{CB} = -10\text{ V}, I_E = 0, f = 1\text{ MHz}$	—	240	—	pF

Marking



Note 2: A line under a Lot No. identifies the indication of product Labels.
 [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

